

## Self Protected High Side Driver with Temperature Shutdown and Current Limit

The NCV8452 is a fully protected High-Side driver that can be used to switch a wide variety of loads, such as bulbs, solenoids and other activators. The device is internally protected from an overload condition by an active current limit and thermal shutdown.

### Features

- Short Circuit Protection
- Thermal Shutdown with Automatic Restart
- CMOS (3 V/5 V) Compatible Control Input
- Overvoltage Protection and Shutdown
- Output Voltage Clamp for Inductive Switching
- Under Voltage Shutdown
- Loss of Ground Protection
- ESD Protection
- Reverse Battery Protection (with external resistor)
- Very Low Standby Current
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These are Pb-Free Devices

### Typical Applications

- Switch a Variety of Resistive, Inductive and Capacitive Loads
- Can Replace Electromechanical Relays and Discrete Circuits
- Automotive / Industrial

### PRODUCT SUMMARY

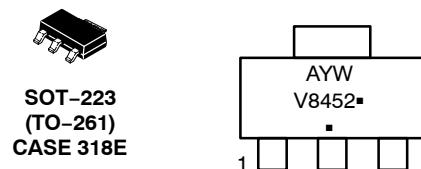
Symbol	Characteristics	Value	Unit
V <sub>OV</sub>	Overvoltage Protection	41	V
V <sub>D</sub>	Operation Voltage	5 – 34	V
R <sub>ON</sub>	On-State Resistance	200	mΩ
I <sub>ILIM</sub>	Output Current Limit	1.0	A



ON Semiconductor®

<http://onsemi.com>

### MARKING DIAGRAM



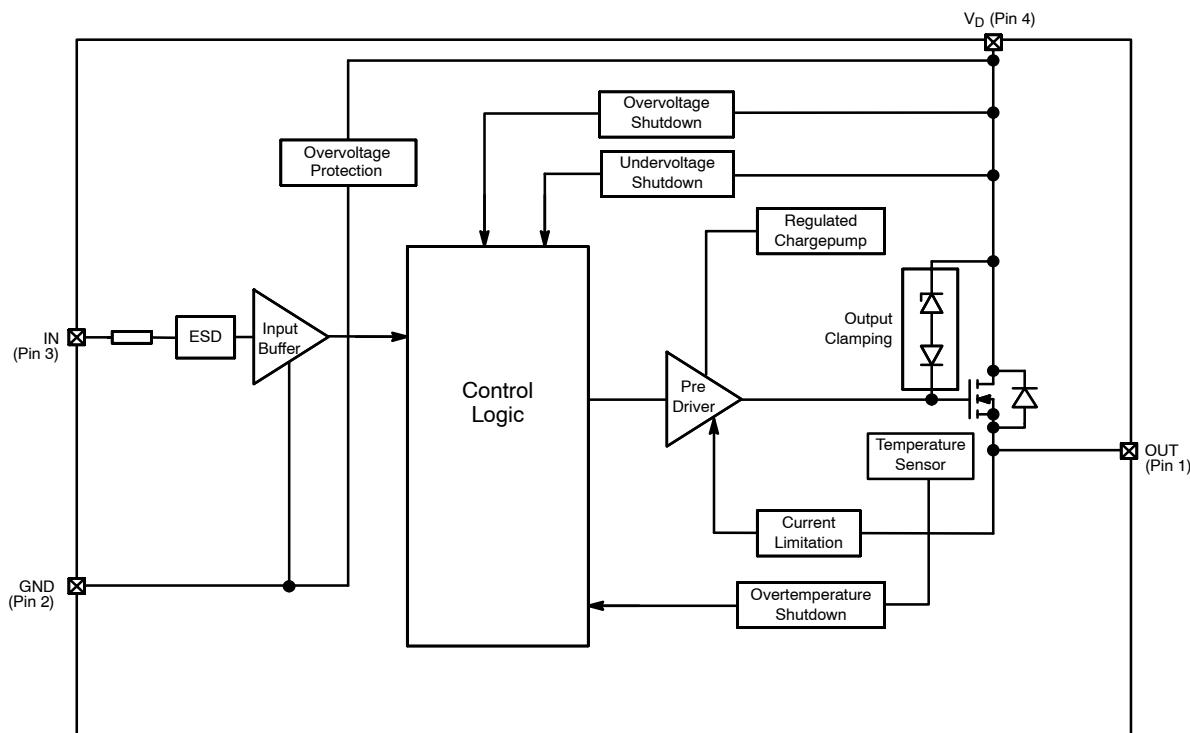
V8452 = Device Code  
A = Assembly Location  
Y = Year  
W = Work Week  
■ = Pb-Free Package

(Note: Microdot may be in either location)

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 12 of this data sheet.

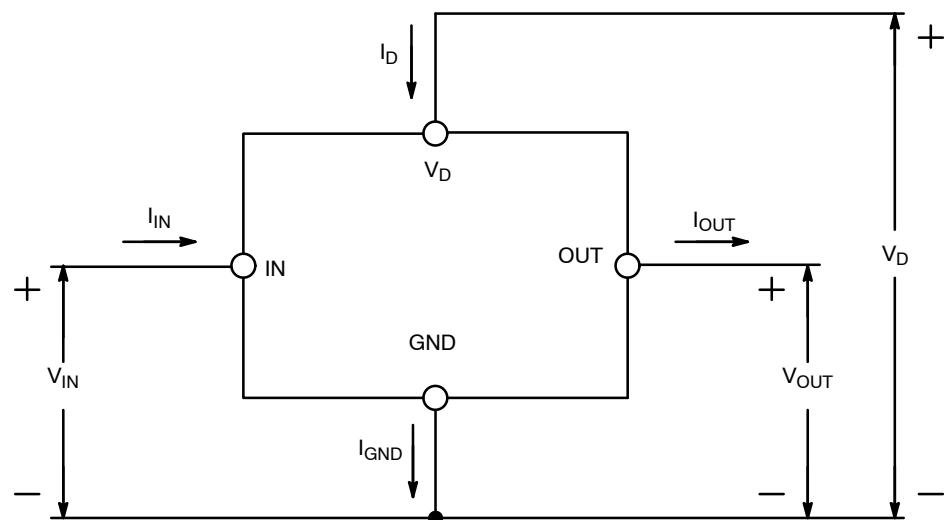
# NCV8452



**Figure 1. Block Diagram**

## PACKAGE PIN DESCRIPTION

Pin #	Symbol	Description
1	OUT	Output
2	GND	Ground
3	IN	Logic Level Input
4	V <sub>D</sub>	Supply Voltage



**Figure 2. Voltage and Current Definition**

**MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
DC Supply Voltage	V <sub>D</sub>	40	V
Peak Transient Input Voltage (Load Dump 46 V, V <sub>D</sub> = 14 V, ISO7637-2 pulse5) (Note 1)	V <sub>peak</sub>	60	V
Input Voltage	V <sub>IN</sub>	-5 to V <sub>D</sub>	V
Input Current	I <sub>IN</sub>	±5	mA
Output Current	I <sub>OUT</sub>	Internally Limited	A
Power Dissipation @T <sub>A</sub> = 25°C (Note 3) @T <sub>A</sub> = 25°C (Note 4)	P <sub>D</sub>	1.19 1.76	W
Electrostatic Discharge (Note 1) (HBM Model 100 pF / 1500 Ω) Input Output V <sub>D</sub>		±1 ±5 ±5	kV
Single Pulse Inductive Load Switch Off Energy (Note 1) (L = 4.55 H, V <sub>D</sub> = 13.5 V; I <sub>L</sub> = 0.5 A, T <sub>Jstart</sub> = 25°C)	E <sub>AS</sub>	0.8	J
Operating Junction Temperature	T <sub>J</sub>	-40 to +150	°C
Storage Temperature	T <sub>storage</sub>	-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Not subjected to production testing
2. Reverse Output current has to be limited by the load to stay within absolute maximum ratings and thermal performance.
3. Minimum pad.
4. 1 in square pad size, FR-4, 1 oz Cu.

**THERMAL RESISTANCE RATINGS**

Parameter	Symbol	Max Value	Unit
Thermal Resistance (Note 5) Junction-to-Lead	R <sub>thJL</sub>	10	°C/W
Junction-to-Ambient (Note 6)	R <sub>thJA</sub>	105	°C/W
Junction-to-Ambient (Note 7)	R <sub>thJA</sub>	71	°C/W

5. Reverse Output current has to be limited by the load to stay within absolute maximum ratings and thermal performance.
6. Minimum pad.
7. 1 in square pad size, FR-4, 1 oz Cu.

**ELECTRICAL CHARACTERISTICS** ( $V_D = 13.5 \text{ V}$ ;  $-40^\circ\text{C} < T_J < 150^\circ\text{C}$  unless otherwise specified)

<b>Rating</b>	<b>Symbol</b>	<b>Conditions</b>	<b>Value</b>			<b>Unit</b>
			<b>Min</b>	<b>Typ</b>	<b>Max</b>	
Operating Supply Voltage	$V_D$		5	–	34	V
Undervoltage Shutdown	$V_{UV}$		2.5		5.5	V
Undervoltage Restart	$V_{UV(\text{res})}$				6.0	V
Undervoltage Hysteresis	$V_{UV(\text{hyst})}$			0.3		
Oversupply Shutdown	$V_{OV}$		34		42	V
Oversupply Restart	$V_{OV(\text{res})}$		33			
On-state Resistance	$R_{ON}$	$I_{OUT} = 0.5 \text{ A}, V_{IN} = 5 \text{ V}, T_J = 25^\circ\text{C}$ $I_{OUT} = 0.5 \text{ A}, V_{IN} = 5 \text{ V}, T_J = 150^\circ\text{C}$		160	200 400	$\text{m}\Omega$
Standby Current	$I_{D(\text{off})}$	$V_{IN} = V_{OUT} = 0 \text{ V}$		12	25	$\mu\text{A}$
Active Ground Current	$I_{GND(\text{on})}$	$V_{IN} = 5 \text{ V}$		1	1.8	mA
Output Leakage Current	$I_{OUT(\text{off})}$	$V_{IN} = 0 \text{ V}$			2	$\mu\text{A}$

**INPUT CHARACTERISTICS**

Input Voltage – Low	$V_{IN(\text{low})}$				0.8	V
Input Voltage – High	$V_{IN(\text{high})}$		2.2			V
Off State Input Current	$I_{IN(\text{off})}$	$V_{IN} = 0.7 \text{ V}$			10	$\mu\text{A}$
On State Input Current	$I_{IN(\text{on})}$	$V_{IN} = 5.0 \text{ V}$			10	$\mu\text{A}$
Input Threshold Hysteresis	$V_{IN(\text{hyst})}$			0.3		V
Input Resistance	$R_I$		1.5	2.8	3.5	$\text{k}\Omega$

**SWITCHING CHARACTERISTICS**

Turn-On Time	$t_{on}$	to 90% $V_{OUT}$ , $R_L = 24 \Omega$		60	120	$\mu\text{s}$
Turn-Off Time	$t_{off}$	to 10% $V_{OUT}$ , $R_L = 24 \Omega$		60	120	$\mu\text{s}$
Slew Rate On	$dV_{OUT}/dt_{on}$	10% to 30% $V_{OUT}$ , $R_L = 24 \Omega$		1	4	$\text{V} / \mu\text{s}$
Slew Rate Off	$dV_{OUT}/dt_{off}$	70% to 40% $V_{OUT}$ , $R_L = 24 \Omega$		1	4	$\text{V} / \mu\text{s}$

**REVERSE BATTERY** (Note 8)

Reverse Battery	$-V_D$	Requires a 150 $\Omega$ Resistor in GND Connection			32	V
Forward Voltage	$V_F$	$T_J = 150^\circ\text{C}$		0.6		V

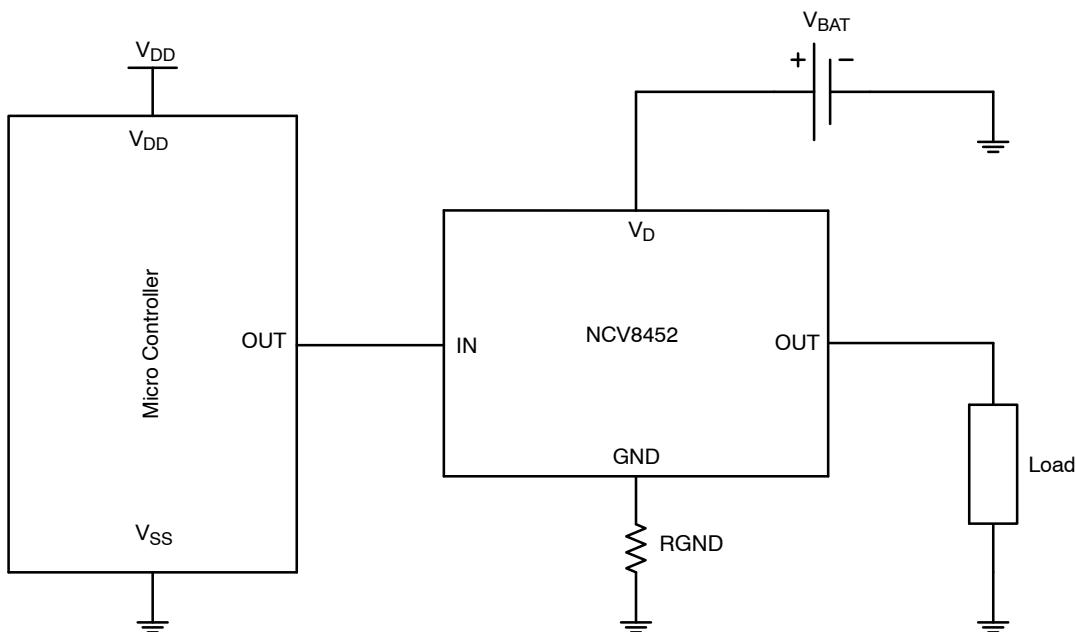
**PROTECTION FUNCTIONS** (Note 9)

Temperature Shutdown (Note 8)	$TSD$		150	175	200	$^\circ\text{C}$
Temperature Shutdown Hysteresis (Note 8)	$TSD_{(\text{hyst})}$			10		$^\circ\text{C}$
Oversupply Protection	$V_{OV}$	$I_D = 4 \text{ mA}$	41			V
Switch Off Output Clamp Voltage	$V_{CLAMP}$	$I_D = 4 \text{ mA}, V_{IN} = 0 \text{ V}$	$V_D - 41$	$V_D - 47$		V
Output Current Limit Initial Peak	$I_{LIM}$	$V_D = 20 \text{ V}, T_J = 25^\circ\text{C}$ $T_J = -40^\circ\text{C to } 150^\circ\text{C}$	1.0	1.8 –	3	A

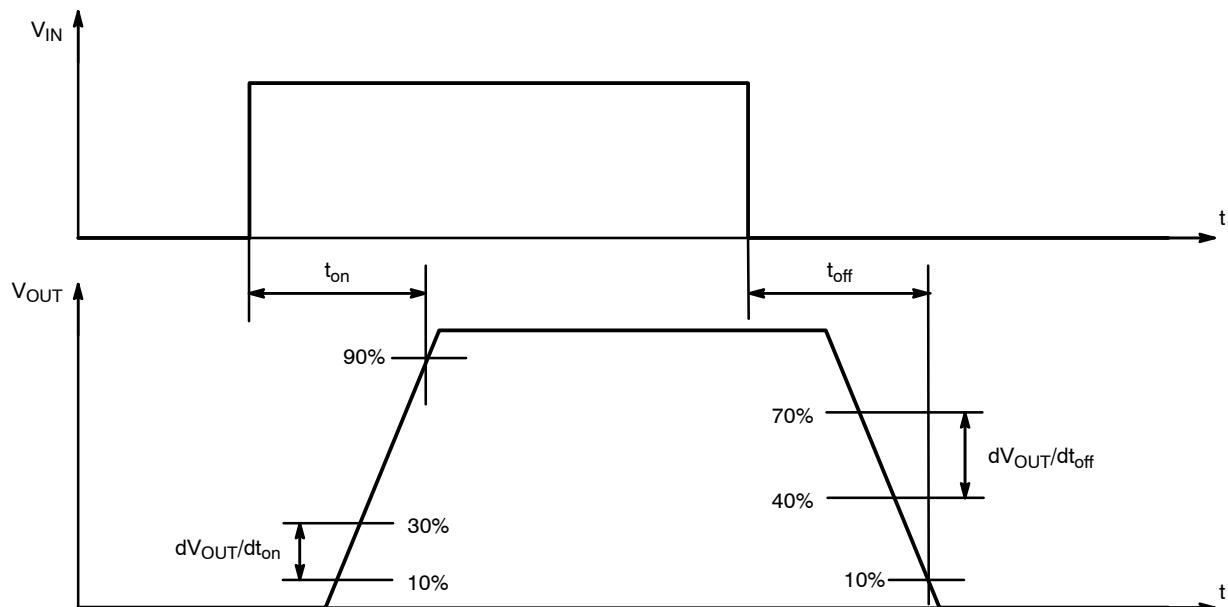
8. Not subjected to production testing

9. To ensure long term reliability under heavy overload or short circuit conditions, protection and related diagnostic signals must be used together with a proper hardware/software strategy. If the device operates under abnormal conditions this hardware/software solution must limit the duration and number of activation cycles.

## NCV8452



**Figure 3. Application Diagram**



**Figure 4. Resistive Load Switching Waveform**

## TYPICAL CHARACTERISTIC CURVES

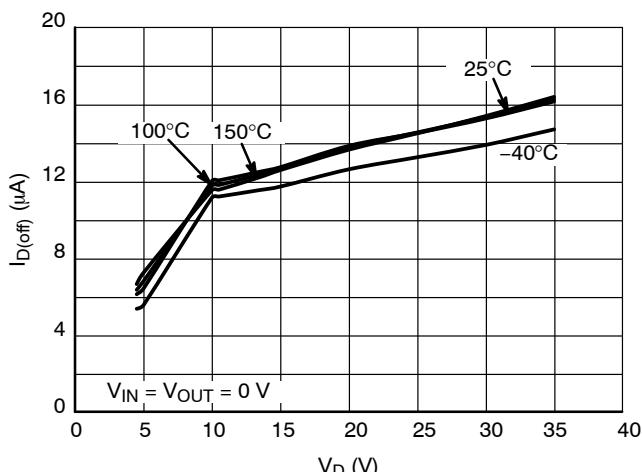


Figure 5. Standby Current vs. Supply Voltage

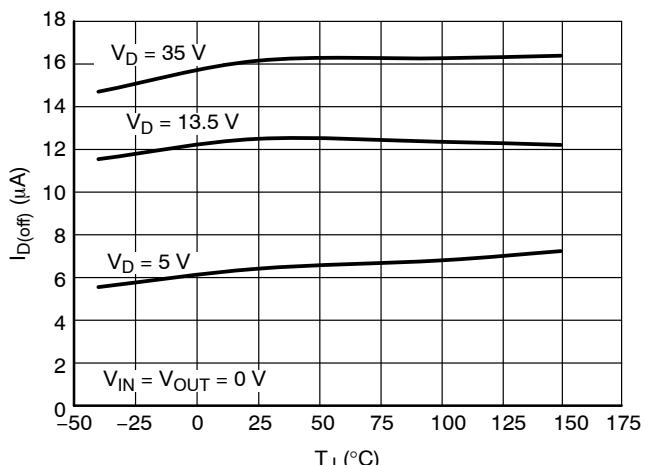


Figure 6. Standby Current vs. Junction Temperature

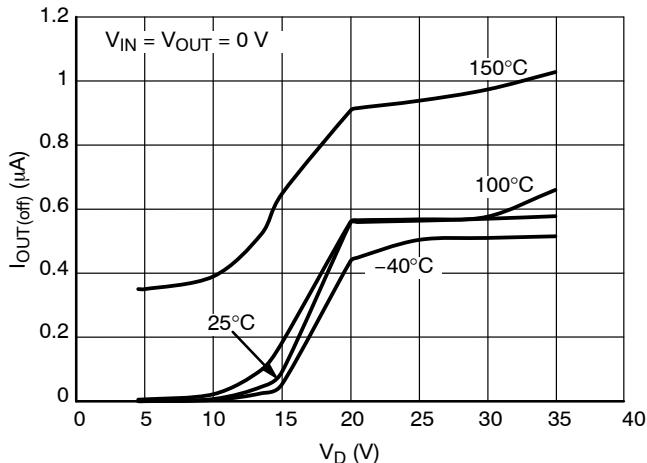


Figure 7. Output Leakage Current vs. Supply Voltage

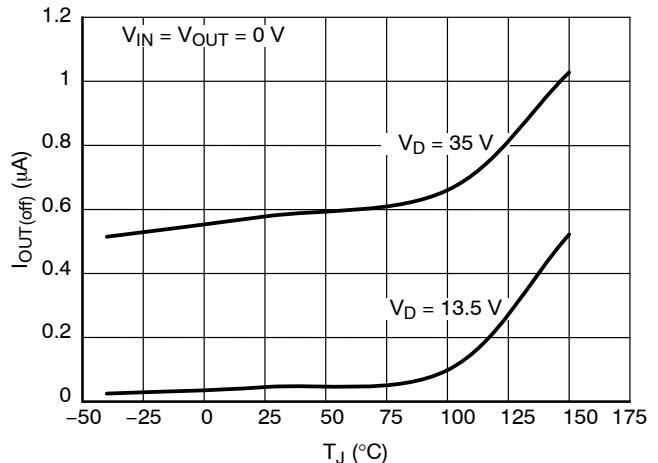


Figure 8. Output Leakage Current vs. Junction Temperature

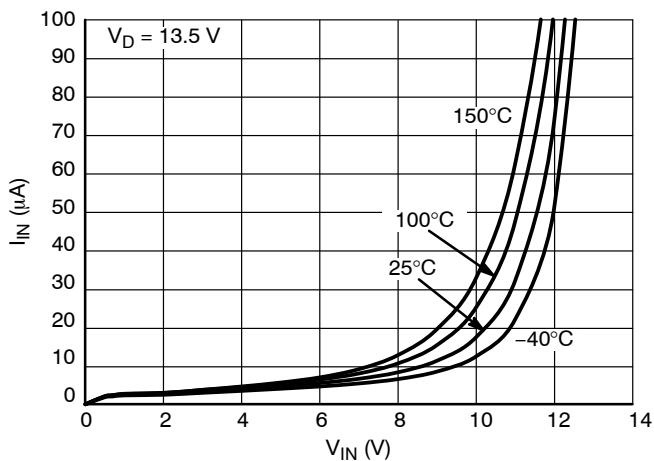


Figure 9. Input Current vs. Input Voltage

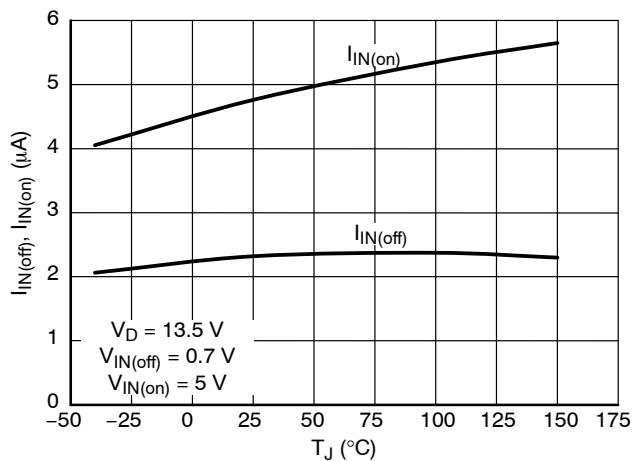


Figure 10. Input Current vs. Junction Temperature

## TYPICAL CHARACTERISTIC CURVES

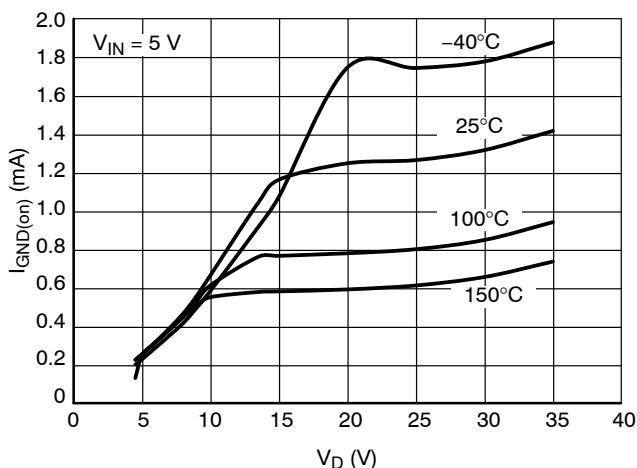


Figure 11. Active Ground Current vs. Supply Voltage

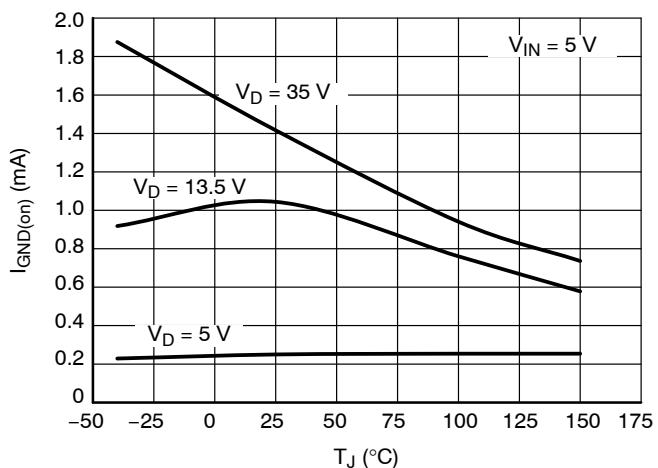


Figure 12. Active Ground Current vs. Junction Temperature

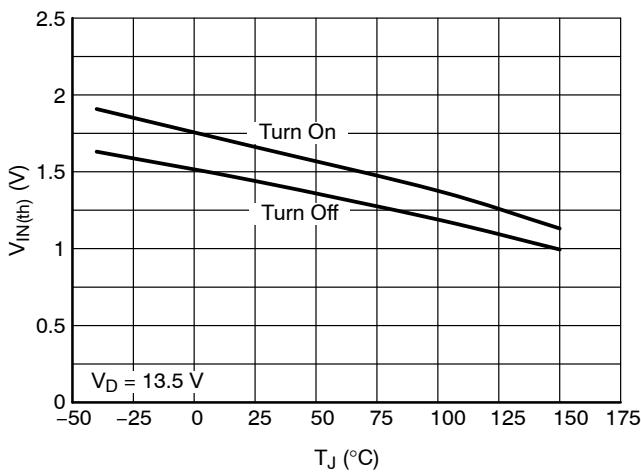


Figure 13. Input Threshold Voltage vs. Junction Temperature

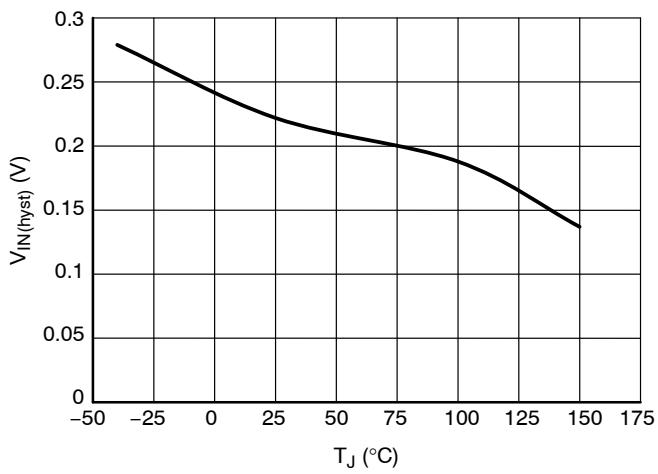


Figure 14. Input Threshold Hysteresis vs. Junction Temperature

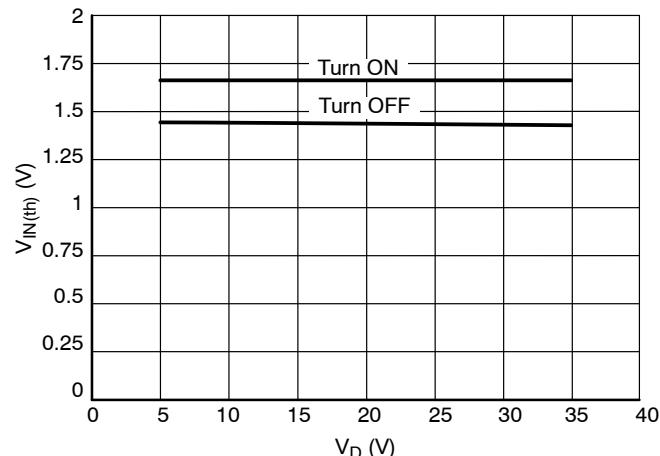
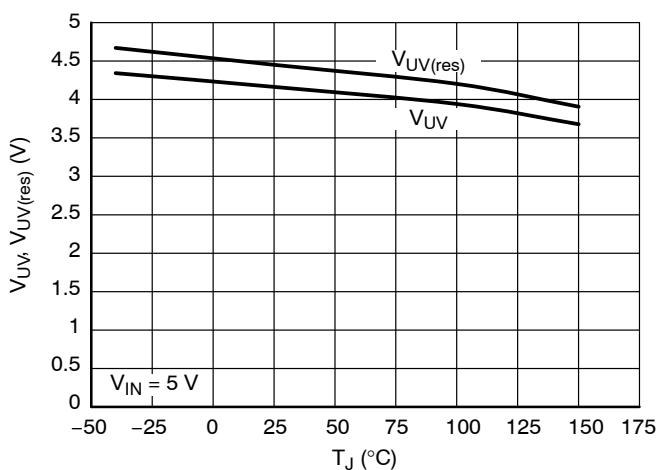
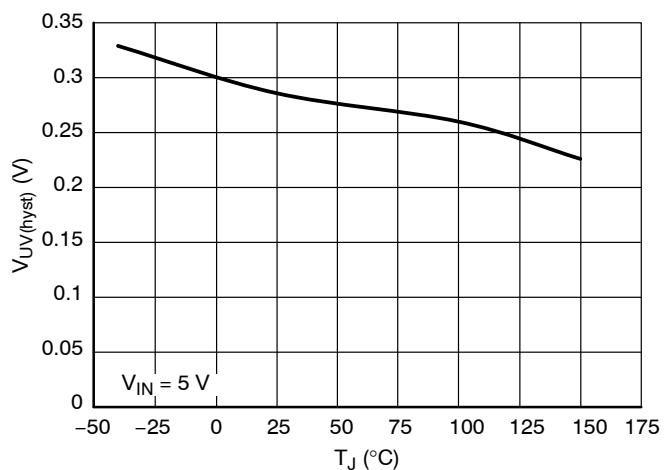


Figure 15. Input Threshold Voltage vs. Supply Voltage

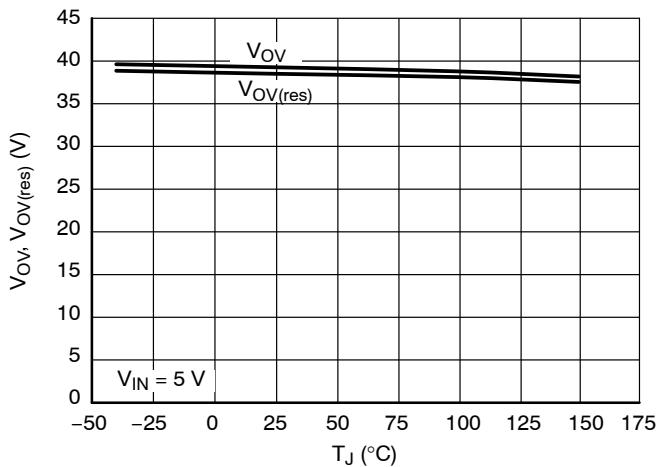
## TYPICAL CHARACTERISTIC CURVES



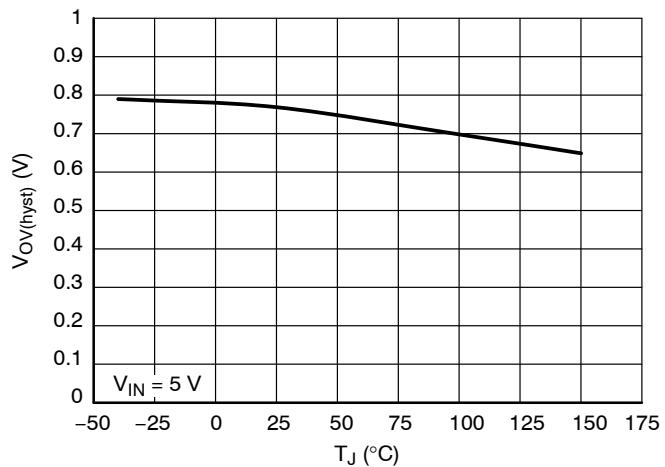
**Figure 16. Under Voltage Shutdown and Restart vs. Junction Temperature**



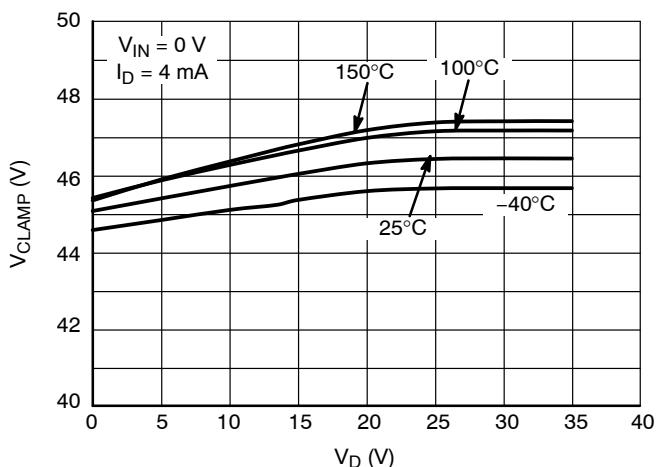
**Figure 17. Under Voltage Shutdown Hysteresis vs. Junction Temperature**



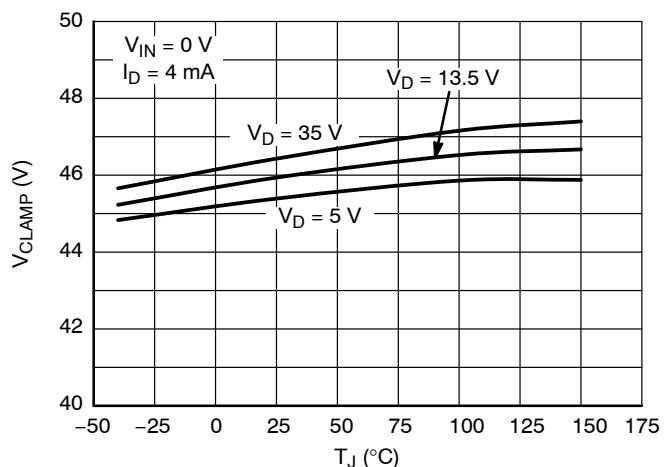
**Figure 18. Over Voltage Shutdown vs. Junction Temperature**



**Figure 19. Over Voltage Shutdown Hysteresis vs. Junction Temperature**

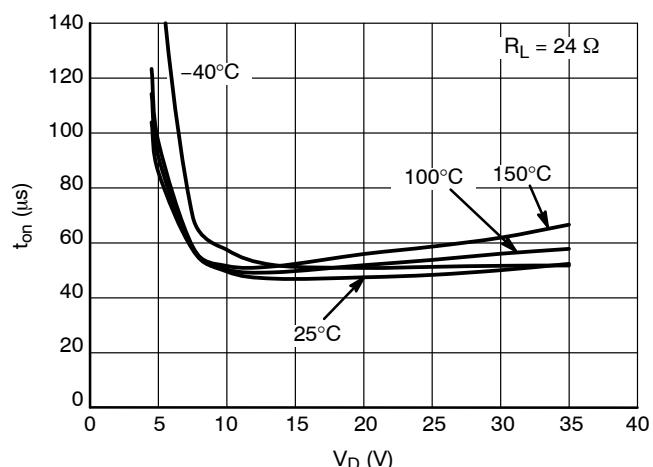
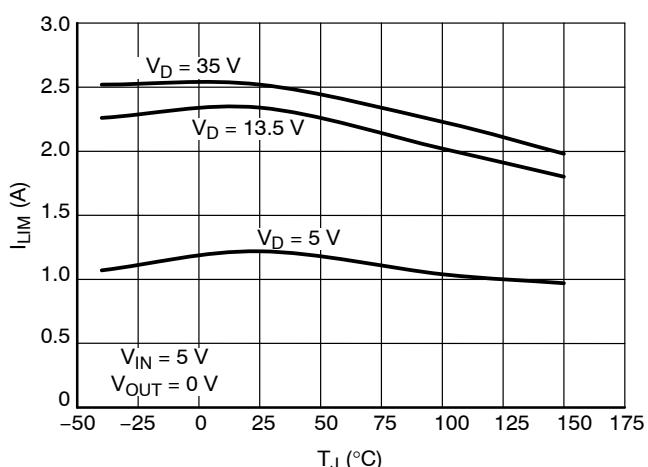
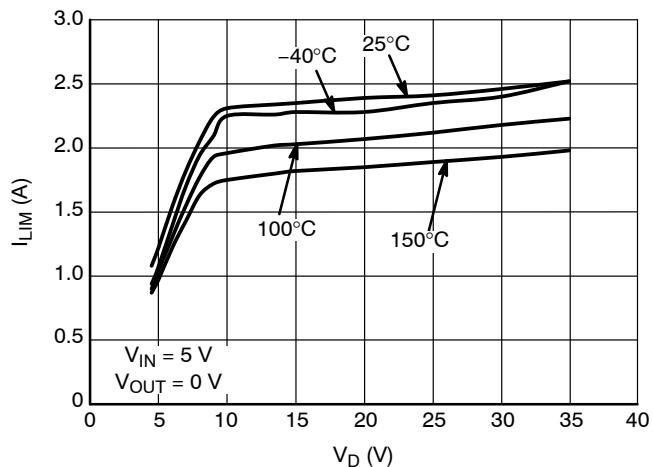
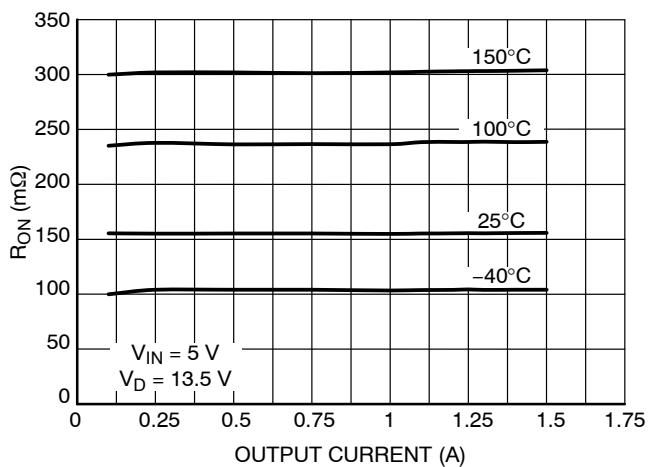
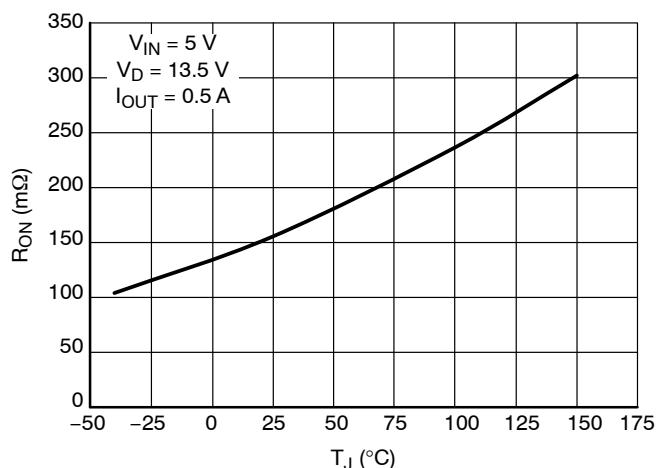
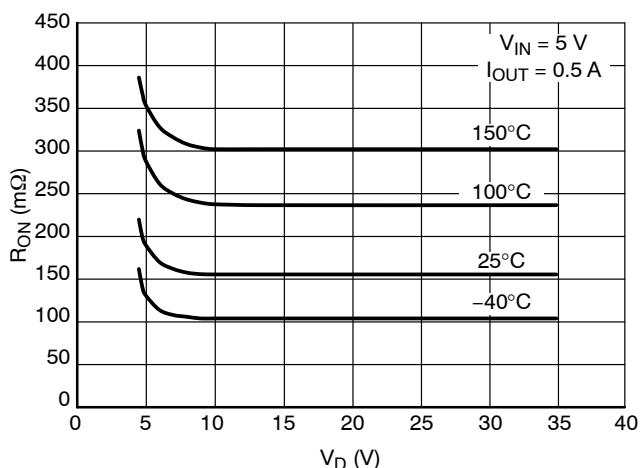


**Figure 20. Output Clamp Voltage vs. Supply Voltage**



**Figure 21. Output Clamp Voltage vs. Junction Temperature**

## TYPICAL CHARACTERISTIC CURVES



## TYPICAL CHARACTERISTIC CURVES

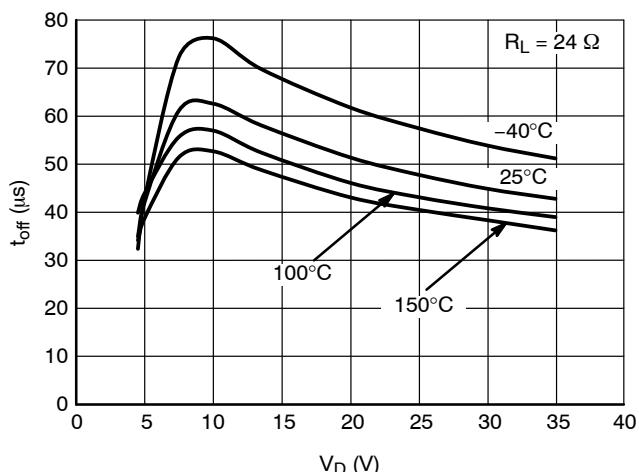


Figure 28. Turn-Off Time vs. Supply Voltage

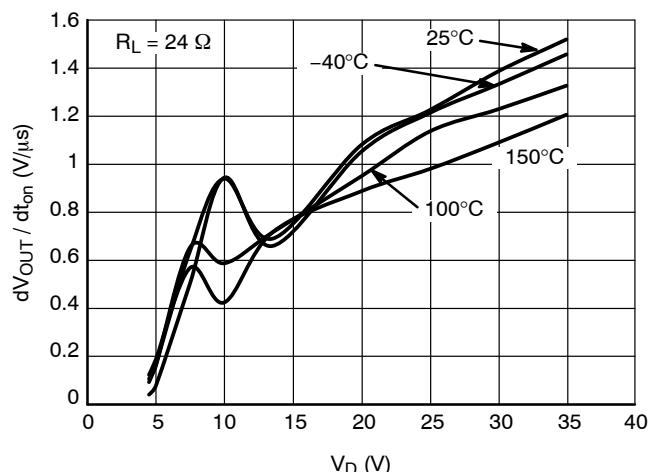


Figure 29. Slew Rate On vs. Supply Voltage

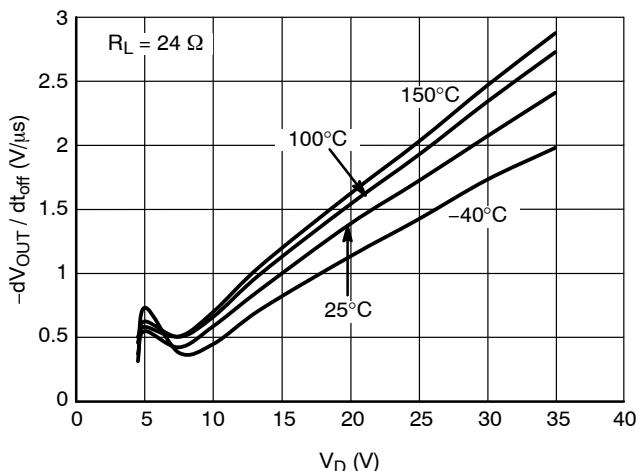


Figure 30. Slew Rate Off vs. Supply Voltage

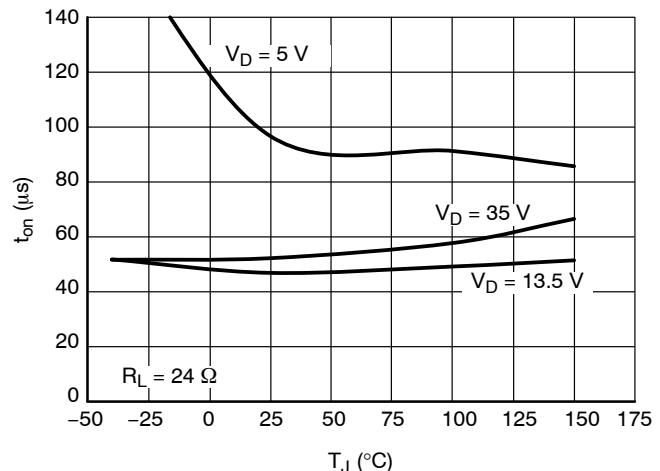


Figure 31. Turn-On vs. Junction Temperature

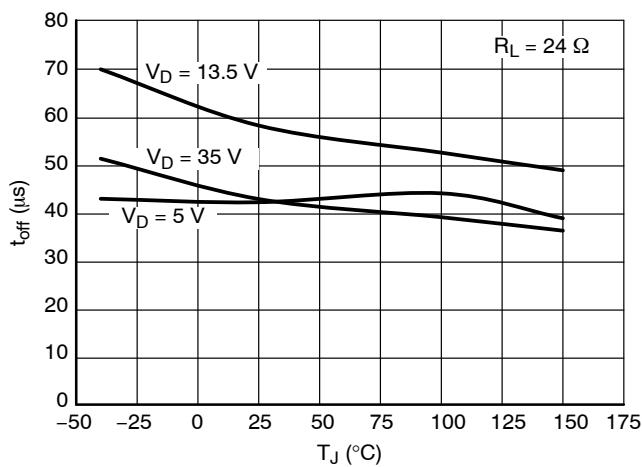


Figure 32. Turn-Off Time vs. Junction Temperature

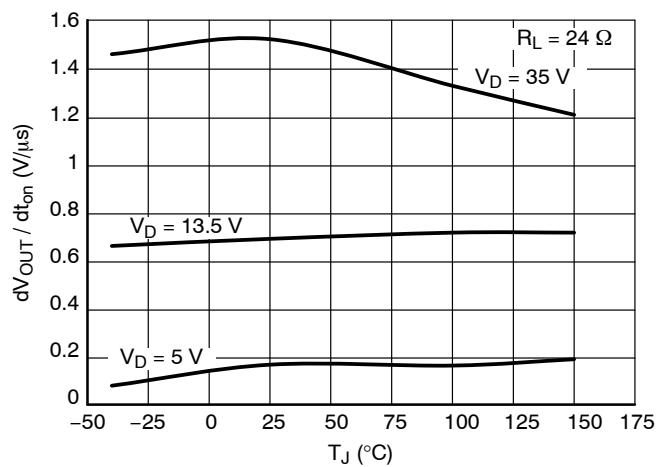


Figure 33. Slew Rate On vs. Junction Temperature

## TYPICAL CHARACTERISTIC CURVES

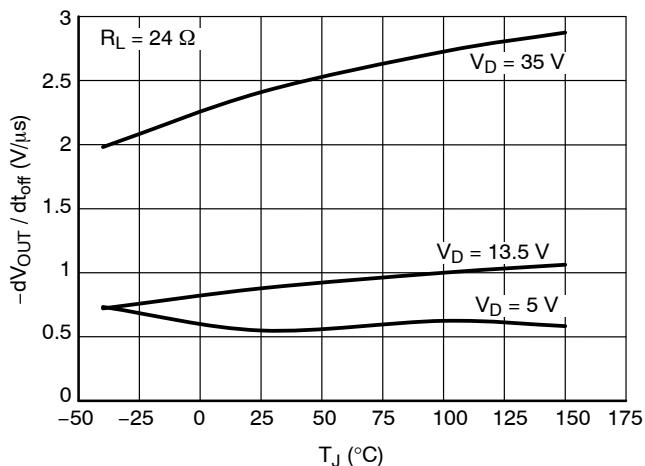


Figure 34. Slew Rate Off vs. Junction Temperature

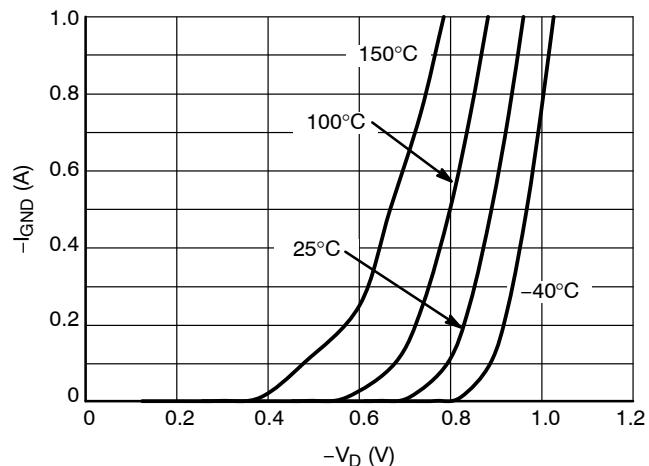


Figure 35. Supply-to-Ground Reverse Characteristics

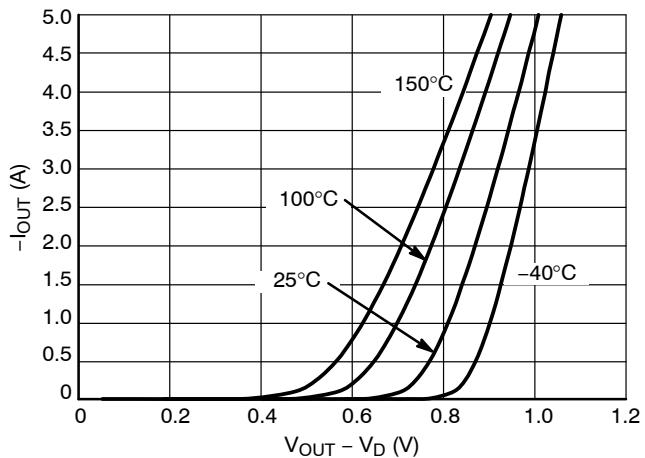


Figure 36. Power FET Body Forward Characteristics

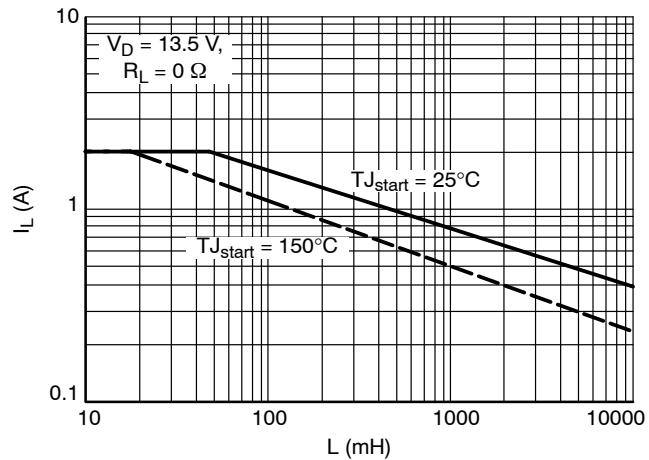


Figure 37. Single Pulse Maximum Switch Off Current vs. Load Inductance

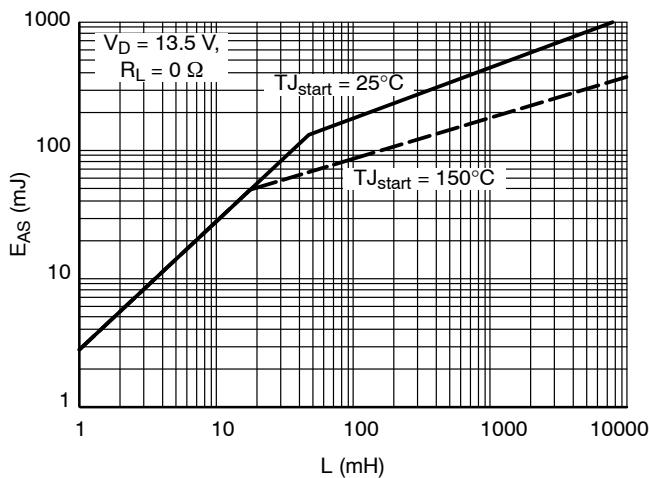


Figure 38. Single Pulse Maximum Switch Off Energy vs. Load Inductance

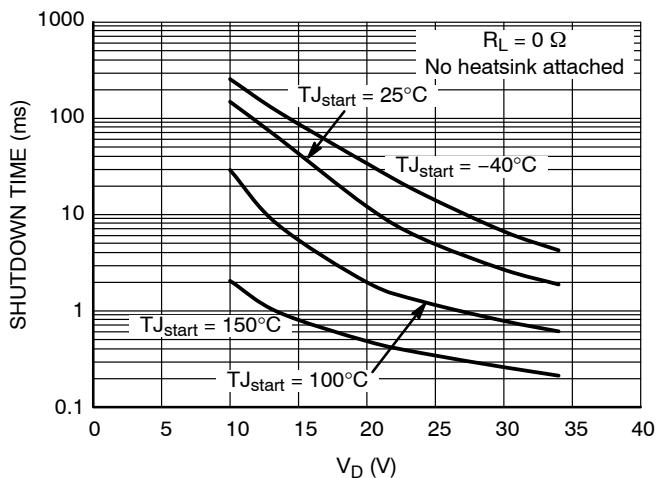
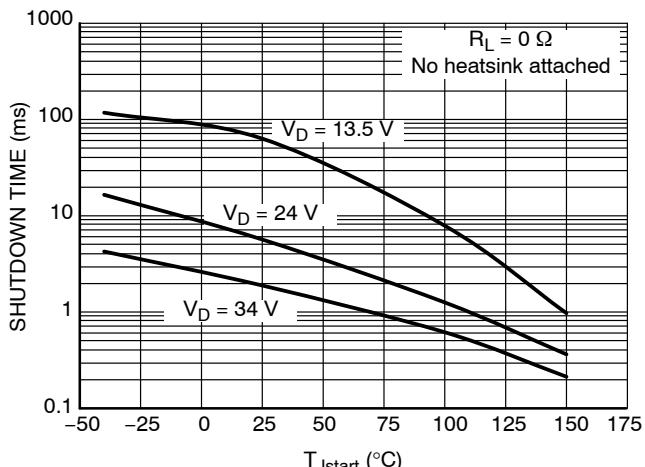
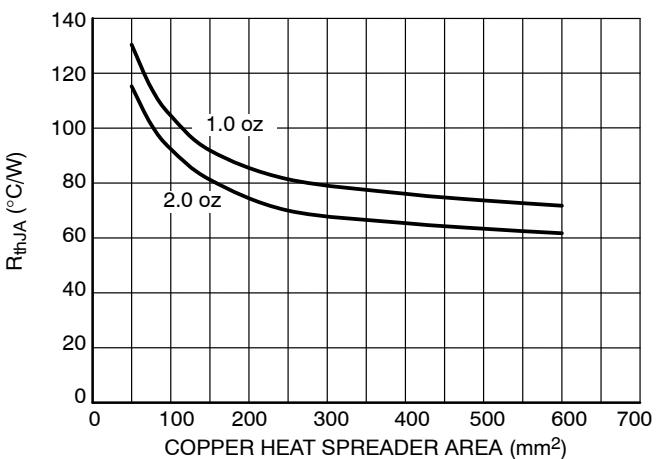


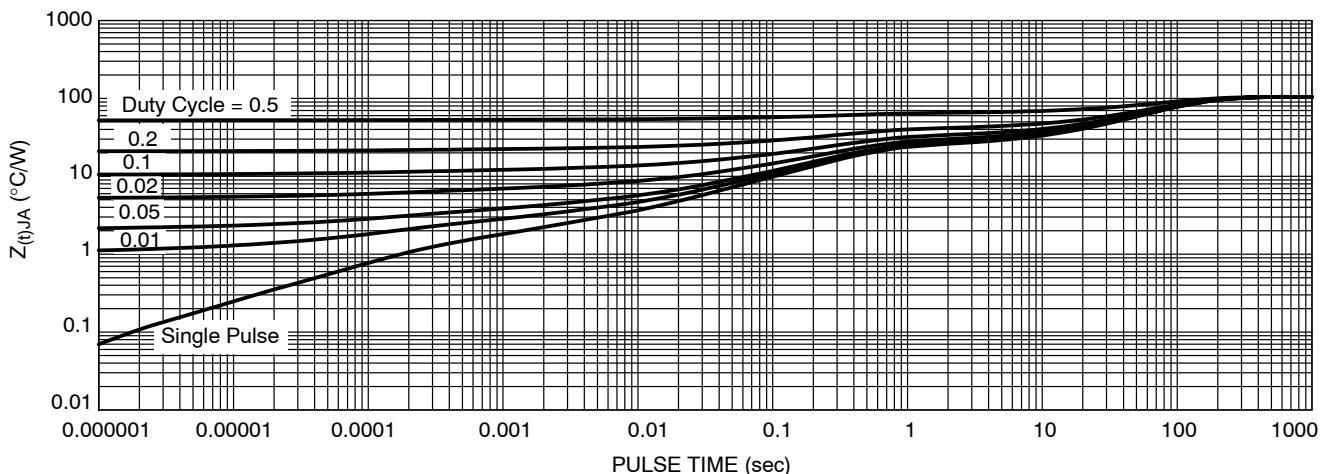
Figure 39. Initial Short-Circuit Shutdown Time vs. Supply Voltage



**Figure 40. Initial Short-Circuit Shutdown Time vs. Starting Junction Temperature**



**Figure 41. Junction-to-Ambient Thermal Resistance vs. Copper Area**



**Figure 42. Junction-to-Ambient Transient Thermal Impedance (minimum pad size)**

## ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
NCV8452STT1G	SOT-223 (Pb-Free)	1000 / Tape & Reel
NCV8452STT3G	SOT-223 (Pb-Free)	4000 / Tape & Reel

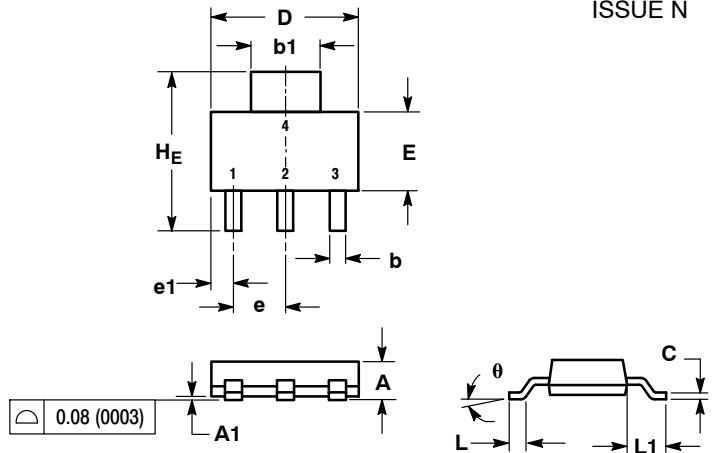
<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## PACKAGE DIMENSIONS

## SOT-223 (TO-261)

CASE 318E-04

ISSUE N

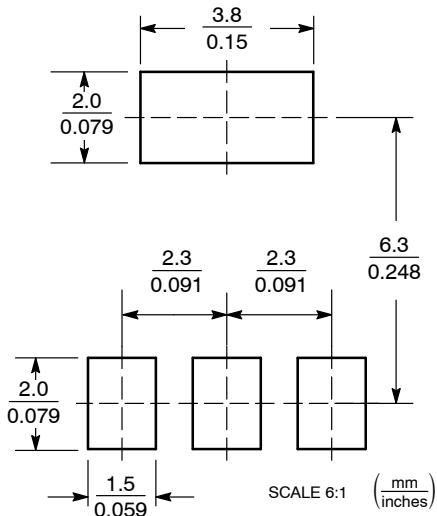


## NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: INCH.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	1.50	1.63	1.75	0.060	0.064	0.068
A1	0.02	0.06	0.10	0.001	0.002	0.004
b	0.60	0.75	0.89	0.024	0.030	0.035
b1	2.90	3.06	3.20	0.115	0.121	0.126
c	0.24	0.29	0.35	0.009	0.012	0.014
D	6.30	6.50	6.70	0.249	0.256	0.263
E	3.30	3.50	3.70	0.130	0.138	0.145
e	2.20	2.30	2.40	0.087	0.091	0.094
e1	0.85	0.94	1.05	0.033	0.037	0.041
L	0.20	---	---	0.008	---	---
L1	1.50	1.75	2.00	0.060	0.069	0.078
H_E	6.70	7.00	7.30	0.264	0.276	0.287
$\theta$	0°	-	10°	0°	-	10°

## SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

**ON Semiconductor** and **ON** are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of SCILLC's product/patent coverage may be accessed at [www.onsemi.com/site/pdf/Patent-Marking.pdf](http://www.onsemi.com/site/pdf/Patent-Marking.pdf). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

## PUBLICATION ORDERING INFORMATION

## LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor  
P.O. Box 5163, Denver, Colorado 80217 USA  
Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada  
Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada  
Email: [orderlit@onsemi.com](mailto:orderlit@onsemi.com)

## N. American Technical Support: 800-282-9855 Toll Free

USA/Canada

## Europe, Middle East and Africa Technical Support:

Phone: 421 33 790 2910

## Japan Customer Focus Center

Phone: 81-3-5817-1050

ON Semiconductor Website: [www.onsemi.com](http://www.onsemi.com)Order Literature: <http://www.onsemi.com/orderlit>

For additional information, please contact your local  
Sales Representative



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

#### Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помошь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помошь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



#### Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: [org@eplast1.ru](mailto:org@eplast1.ru)

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.